



**ELECTRONIC COPY**

LG652472301  
Report verification at igi.org



September 19, 2024

IGI Report Number **LG652472301**

Description **LABORATORY GROWN DIAMOND**

Shape and Cutting Style **EMERALD CUT**

Measurements **6.73 X 4.89 X 3.00 MM**

**GRADING RESULTS**

Carat Weight **1.01 CARAT**

Color Grade **D**

Clarity Grade **VS 1**

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**GRADING RESULTS**

Carat Weight **1.01 CARAT**

Color Grade **D**

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**ADDITIONAL GRADING INFORMATION**

Polish **EXCELLENT**

Symmetry **VERY GOOD**

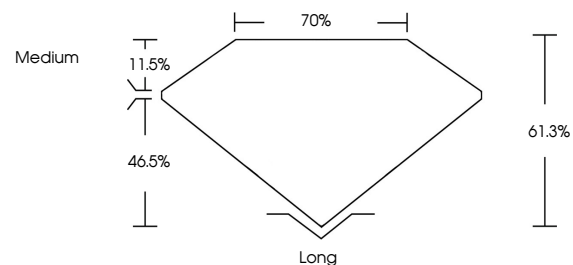
Fluorescence **NONE**

Inscription(s) **IGI LG652472301**

Comments: As Grown - No indication of post-growth treatment.

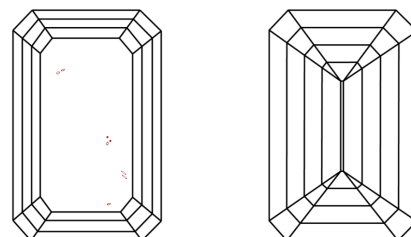
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

**PROPORTIONS**



Sample Image Used

**CLARITY CHARACTERISTICS**



**KEY TO SYMBOLS**

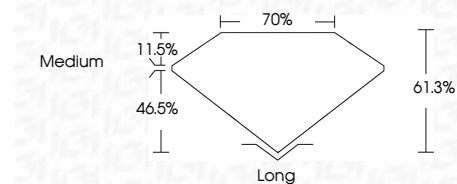
Red symbols indicate internal characteristics.  
Green symbols indicate external characteristics.

**COLOR**

D E F G H I J Faint Very Light Light

**CLARITY**

IF	VS <sup>1-2</sup>	VS <sup>1-2</sup>	SI <sup>1-2</sup>	I <sup>1-3</sup>
Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included



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**IGI**



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**EMERALD CUT**

**6.73 X 4.89 X 3.00 MM**

**1.01 CARAT**

**D**

**VS 1**

**61.0%**

**70%**

**Medium**

**Long**

**EXCELLENT**

**VERY GOOD**

**NONE**

**IGI LG652472301**

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